Therm alcom pression of two-dim ensional atom ic hydrogen to quantum degeneracy

S. Vasilyev,¹ J. Jarvinen,¹ A. J. Safonov,² and S. Jaakkola¹

¹W ihuri Physical Laboratory, Department of Physics, University of Turku, 20014 Turku, Finland ²Laboratory of Metastable Quantum Systems, ISSSP, RRC Kurchatov Institute, 123182 Moscow, Russia

(D ated: M arch 22, 2024)

W e describe experim ents where 2D atom ic hydrogen gas is com pressed them ally at a sm all "cold spot" on the surface of super uid helium and detected directly with electron-spin resonance. We reach surface densities up to 5 10^{12} cm² at tem peratures 100 mK corresponding to them axim um 2D phase-space density 1:5. By independent measurements of the surface density and its decay rate we make the rst direct determination of the three-body recombination rate constant and get the upper bound L_{3b} . 2 10^{25} cm⁴/s which is an order of magnitude sm aller than previously reported experimental results.

PACS num bers: 05.30 Jp, 67.65.+ z, 82.20 Pm

W hen adsorbed on the surface of super uid helium spin-polarized atom ic hydrogen (H #) is an ideal realization of a two-dimensional (2D) boson gas [1]. Helium provides a translationally invariant substrate and its surfacenorm alpotential supports only one bound state for hydrogen with the binding energy $E_a = 1.14(1) \text{ K}$ [2]. Even for such a weak interaction, low ering the surface tem perature T_s well below 1 K leads to a large adsorbate density . At high H # coverages three-body recom bination is expected to be the dom inant density decay m echanism setting the main obstacle to the achievem ent of the guantum degeneracy regime, where the therm alde Broglie wavelength is larger than the average interatom ic spacing. Degenerate 2D H # is expected to exhibit collective phenom ena such as the K osterlitz-T houless super uidity transition and the form ation of a quasicondensate.

Twom ethods of local com pression of adsorbed H # have been em ployed to overcom e lim itations caused by recom bination and its heat. Magnetic compression has been successfully used to achieve quantum degeneracy [3, 4]. In this method the recombination heat is removed from the compressed H # by ripplons of the helium surface and the cooling e ciency depends on the length of the heat transfer path. By decreasing the size of the com pressed region to 20 m we were able to achieve 2 9 31. However, the small size of the sample together with large magnetic eld gradients did not allow to implement direct diagnostics of adsorbed H #. In the therm al compression method [5, 6] cooling a sm allpart of the sam ple cellwall well below the tem perature of the rest of the wall leads to an exponential increase of on such a "cold spot". In this method the recombination heat is transferred from the ripplons to the phonons of helium [7] and then to the substrate beneath the spot. Therefore a larger spot is preferable as long as the total recombination rate on the spot becomes a limitation. The larger sample size and the hom ogeneity of the magnetic eld make therm al com pression better suited for direct studies of adsorbed

н#.

In the present work we use sensitive electron-spin resonance [8] to diagnose 2D H # gas therm ally compressed to 2 1.5 and discuss the limitations and possible in – provem ents of the "cold spot" method to reach and detect the K osterlitz-T houless transition. By independent measurem ents of the recombination rate and the surface density we obtain the rst directly determ ined value, actually an upper bound, of the three-body surface recombination rate constant L_{3b} . 2 10 25 cm⁴/sec. This is 4...10 times sm aller than the earlier values measured indirectly [3, 9, 10, 11].

Our experimental setup is shown in Fig.1. The sam ple cell has been described elsewhere [8]. The lowtem perature part of the ESR spectrom eter, operating now as a mm-wave bridge, has been modied so that we may use three times smaller excitation powers and thus avoid ESR instability e ects [8] in a wider tem peratures range. G radient coils were built to reduce the eld inhom ogeneity of the main magnet so that the width of the bulk line is decreased to 0:1 G. It has been found that even very small (1 ppb)³He impurity in our isotopically puried ⁴He condensed into the cellm ay significantly in uence the adsorption of the 2D hydrogen [2]. Therefore we built an in situ helium Im purier, a reservoir with the large surface area of 2 10^3 cm² located in zero eld (Fig.1). Being cooled down to the lowest tem peratures attained here the puri er adsorbs the rem inder of ³He atom s from the cell. The m iniature R uO $_2$ therm om eters used to measure the tem peratures of the cell, the bu er volume and the ${}^{3}\text{He}/{}^{4}\text{He}$ coolant of the cold spot were calibrated to an accuracy better than 1 mK with a 3 He melting curve therm on eter.

In a typical experiment we llthe cell and the buer with atom ic hydrogen from a low-temperature dissociator to a density n 10^{15} cm³. A fler switching o the discharge we stabilize the buer to $T_b = 350$ mK, the optimum temperature for getting the longest lifetime for



FIG.1: (a) Scheme of the cell. SC = sam ple cell, CS = cold spot, BV = bu er volume, HP = helium puri er; (b) Fabry-Perot resonator with the cold spot in the center of its at mirror; (c) M icrowave eld pro le on the cold spot.

the hydrogen sam ple, and cool the cell to a desired tem perature $T_c = 60...170 \text{ m K}$. The tem peratures of the m ixing chamber of the dilution refrigerator and the ${}^{3}\text{H}e^{-4}\text{H}e$ stream cooling the cold spot (cp. Fig.1) are stabilized in the range $T_L = 30...150 \text{ m K}$. Therm alcom pression can be rapidly (< 5 s) turned on and o by changing the coolant tem perature. Decays of our H # sam ples were governed by impurity relaxation from "pure" hyper ne state b to m ore reactive state a [12]. To decrease the relaxation rate the cell is made of nonmagnetic materials (ultrapure copper, epoxy, K apton foils) and its walls are coated at low tem peratures with a 10..50 nm thick solid H_2 layer by running the dissociator for several days. The 0.2 cm diam eter tube connecting the bu er and the cell is wide enough to render the exchange of atom s between the two volum es faster than the decay rates. This ensures a dynam ic density equilibrium between the volumes. Decays of H # sam ples were m on itored at xed tem peratures of the cell region. Recombination rates in the bu er and cell are measured calorim etrically from the feedback powers of the respective tem perature controllers. We nd that at the present tem peratures the loss rate of atom s in the bu er is negligible com pared to that in the cell. Integrating the latter we extract the bulk densities as functions of time in both volumes.

The evolution of the ESR spectrum during the decay of a H # sample is shown in Fig. 2. The resonance line originating from the adsorbed atom s is shifted from the bulk line due to the non-zero average dipolar eld in this 2D system [8, 13]. To nd the surface density we integrate the surface and bulk absorption ESR lines. The bulk integral is calibrated calorim etrically against the absolute value of the bulk density, which method does



FIG.2: Evolution of (a) H # ESR spectrum and (b) surface density pro le during the decay of a H # sample. The traces were recorded at intervals of 500 s at $T_{\rm L}$ = 45 m K and $T_{\rm c}$ = 112 m K.The dashed line m arks the edge of the cold spot.

not rely on the adsorption isotherm and yields the absolute value of surface density with an accuracy of 10%. W ith this method we checked the relation between the internal dipolar eld and the surface density and found H $_{\rm d}$ = A , where A = 1:05(10) 10 12 G cm². This direct and m ore accurate m easurem ent agrees well with the previous experimental and calculated results [8, 13].

The ESR lineshape of adsorbed atom sS (h) as a function of magnetic eld sweep h is broadened due to the inhom ogeneity of the tem perature T_s (r) and, consequently, density (r) of the 2D gas in the spot region. It is given by the relation

S (h)
$$H_{1}^{2}$$
 (r) f_{i} (h A (r)) (r) rdr; (1)

where H $_1^2$ (r) is them icrowave eld prole on the atmirror. The intrinsic lineshape $f_i(h)$ of the adsorbed atom s is very narrow [8] and can be replaced by a delta function. We used Eq. (1) to extract density proles (r) from the observed lineshapes using a numerical tting routine. Examples of the surface density proles recovered for a few ESR spectra is presented in Fig. 2b. Even for the largest temperature di erence between the cell and spot the surface density is hom ogeneous within 10% on the cold spot. The relatively slow decrease of outside the spot (r > 0:75 cm) gives rise to a broad maximum between the bulk and main surface signals.

Numerous decays have been measured at various cell and spot temperatures. P lots of the maximum surface density as a function of the bulk density n for a xed $T_c=154\,\text{mK}$ and various coolant temperatures T_L are pre-



FIG.3: (a) Maximum surface density on the cold spot for $T_{\rm C}=154$ mK and various $T_{\rm L}$. (b) E ective surface temperatures $T_{\rm s}$ calculated using adsorption isotherm .

sented in Fig. 3a. For low bulk densities the surface density increases linearly with n, as it should do according to the adsorption isothem [5, 14]. E ective temperature of the 2D gas T_s (Fig. 3b) is extracted from the and n values using the adsorption isotherm and taking $E_a = 1.14(1)$ K [2]. At high temperatures T_L & 100 m K and small di erences T_L T_c . 10 m K, T_s turns out be equal to T_L within 1 m K, the error bar of our therm om – etry. This coincidence is regarded as a con section of the above mentioned adsorption energy value.

The observed levelling of with increasing n (upper plots in Fig. 3) points to an overheating of the 2D H # gas which begins the earlier the low er is the coolant tem – perature. The surface tem peratures T_s extracted from the low density parts of the curves start to exceed the coolant tem perature, the di erence increasing with increasing T_c T_L . This may be explained by heating of the spot by a heat ux from the much warm er cell walls. A nother possible reason for the saturation of the surface density could be a 2D hydrodynam ic ow of H # on the spot out of the high density region. If the ow becomes fast enough, the balance between the adsorption and desorption rates will be disturbed. Interaction of H # with surface quasiparticles like ripplons and ³He im purities should in pede the ow. To distinguish between

the roles of the overheating and the 2D $\,$ ow we added ${}^{3}\text{He}$ into the cell varying the ${}^{3}\text{He}$ surface density up to 10^{14} cm 2 . This did not help to get any higher density for the adsorbed H #. On the other hand, the maximum

appeared to be very sensitive to the rate of one-body in purity relaxation in the cell and bu er. Therefore we conclude that the recombination overheating is more im - portant than the 2D ow and lim its the highest achieved densities. The T_s values extracted from the adsorption isotherm (Fig. 3) can be considered as good upper lim its to the real surface tem peratures.

In our experiments the decay of H # is determined m ainly by one-body relaxation and three-body recom – bination on the cell walls. Due to the density pro le over the spot at high being nearly step-like (Fig. 2) we can separate the spot contribution and write for the total recombination rate

$$\frac{dN}{dt} = (2G_1 + L_{3b}^{3})A_{cs} R (n;T_c;T_b); \quad (2)$$

where G_1 is the one-body relaxation rate constant, L_{3b} the three-body recombination rate constant, A cs the cold spot surface area and R (n;T_c;T_b) is the atom loss rate in the rest of the cell and the bu er. We tried to extract the spot contribution by monitoring recombination powers during decays at di erent coolant tem peratures and keeping conditions in the rest of the cell region unchanged. No di erence was found within the noise of the tem perature controller signal indicating that the spot contribution is very small compared to that of the rest of the walls. Therefore, to get a higher resolution, we used the possibility to turn the spot cooling rapidly on (or o) during the decay (Fig. 4) and perform ed such experim ents at various cell tem peratures and bulk densities. Even for the largest change in the surface density of the spot the corresponding change of the total recom bination power in the cell was hardly discernible from the noise. A ssum ing that three-body recombination is the dom inant loss mechanism on the spot and integrating the three-body rate over the actual density pro le of the spot we extract the upper lim it L_{3b} 2 10 25 cm 4 /s. This is the rst directly measured value based on independent determ inations of the recombination rate and surface density. It agrees well with the calculations of de Goey et al. [15], but is an order of magnitude low er than the L_{3b} values reported in several previous works [9, 10, 11].

In all previous m easurem ents of surface recombination was inferred into the rate equations through the adsomption isotherm. Instead of Eq. (2) a rate equation for the bulk density

$$\frac{dn}{dt} = G_1^e n \quad L_{3b}^e n^3; \qquad (3)$$

was used. Here $G_1^e = G_1 (A=V) \exp(E_a=T_S)$ and $L_{3b}^e = L_{3b} (A=V)^{-3} \exp(3E_a=T_S)$ are elective rate constants with A=V being the area-to-volume ratio of the



FIG. 4: Change in recombination power when the temperature of the cold spot is rapidly decreased from 107 to 50 mK and the surface density increases from 1 10^{12} cm² to 3:6 10^{12} cm².

cell. The e ective constants were extracted from the ts of the measured n (t) curves and the adsorption energy and the intrinsic constants G₁ and L_{3b} were obtained from the Arrhenius plots of the e ective constants. There are however two fundam ental draw backs in this approach. First, E_a and the intrinsic rate constants are correlated param eters, and even a small uncertainty in E_a can seriously a ect the accuracy of the intrinsic constants. A ³He content as sm all as 0.1 ppm can be a reason for some of the published values of E_a being 10% lower than the latest value $E_a = 1.14(1)$ K obtained for isotopically puried ⁴He [2] and con med also in this work. At T_s 100 mK this error decreases the factor $\exp(3E_a=T_s)$ and increases L_{3b} by an order of magnitude. Another problem arises from the uncertainty of T_s due to the recombination heating of the 2D gas. This makes the surface tem perature a function of time in the decays and does not allow to use Eq. (3) with G_1^e and L_{3b}^e being constant. In the present method we do not rely on the adsorption isotherm, but the error in L_{3b} is determined only by the absolute inaccuracy of and is at most 30%.

Appearance of a super uid 2D H # on the cold spot is expected to manifest itself as an abrupt change of the density pro le and ESR lineshape. In this work super uidity was not yet observed. The highest surface density 5 10^{12} cm² was achieved at T_s 100 m K corresponding to the quantum degeneracy degree of about 1.5. Low ering the tem perature of the sam ple cell below 110 m K or increasing the bulk density above n $2 10^{14}$ $\,\mathrm{cm}^{-2}$ was found to excessively increase the recombination rate on the cell walls thus overheating the 2D H # on the cold spot. On the other hand, when the cell walls were warm er than 150 mK we could not cool the spot su ciently due to a heat ux through the spot substrate and therm alaccom odation of the atom s from the bulk. W hen

designing the cell, three-body recombination on the spot was thought to be faster than what it turned out to be and this was the reason to lim it the spot size. However, one-body surface relaxation outside the spot was observed to give the dom inant contribution to the decay of the sample and appeared to be the main limitation in the present experiments. We succeeded in decreasing the rate of one-body relaxation to G_1 7 10^{2} s 1 at T_c 100 mK, sm allest ever reported in H # experim ents [4, 9, 10, 11]. Yet in future experim ents one should nd a way to reduce the G_1 even further, e.g., by covering the cell walls with a diam agnetic insulating m aterial [14]. A notherm odi cation to get higher surface densities and to make the study of surface recombination m ore quantitative would be to make the cold spot larger and therm ally better insulated from the cell. On the basis of the upper lim it for L_{3b} obtained in the present work we estimate that such modi cations would result in an increase of the degeneracy parameter 2 & 3, where the three-body recombination probability starts to decrease due to quantum correlation e ects [3].

We thank I.I. Lukashevich and AA.Kharitonov for collaboration.This work was supported by the A cadem y ofFinland,W ihuriFoundation, INTAS, the Russian Ministry of Industry, Science and Technology and the RFBR.

E lectronic address: servas@ utu.

- For a review, see J. T. M. W alraven, in Fundam ental Systems in Quantum Optics, edited by J. Dalibard, J. M. Raimond, and J. Zinn-Justin (Elsevier, Amsterdam, 1992), p. 485.
- [2] A.I.Safonov et al, Phys. Rev. Lett. 86, 3356 (2001).
- [3] A.I.Safonov, S.A.Vasilyev, I.S.Yasnikov, I.I.Lukashevich, and S.Jaakkola, Phys. Rev. Lett. 81, 4545 (1998).
- [4] A. P. Mosk, M. W. Reynolds, T. W. Hijmans, and J.T.M. Walraven, Phys. Rev. Lett. 198, 4440 (1998).
- [5] B.V.Svistunov, T.W. Hijmans, G.V.Shlyapnikov, and J.T.M.Walraven, Phys. Rev. B 43, 13412 (1991).
- [6] A.M atsubara et al, Physica B 194-196, 899 (1994).
- [7] M.W. Reynolds, I.D. Setija, and G.V. Shlyapnikov, Phys. Rev. B 46, 575 (1992).
- [8] S.A. Vasilyev et al, Phys. Rev. Lett. 89, 153002 (2002).
- [9] R. Sprik, J. T. M. Walraven, G. H. van Yperen, and I. Silvera, Phys. Rev. B 34, 1986 (1986).
- [10] D.A.Bellet al, Phys. Rev. B 34, 7670 (1986).
- [11] M.W. Reynolds et al., Phys. Rev. B 31, 7503 (1985).
- [12] I. F. Silvera and J. T. M. Walraven, Progress in Low Temperature Physics, vol. X (North-Holland, Amsterdam, 1986), p. 139.
- [13] I. Shinkoda and W . N. Hardy, J. Low Temp. Phys. 85, 99 (1991).
- [14] A. P. Mosk, PhD. thesis, University of Amsterdam (1999).
- [15] L.P.H. de Goey, J.P.J.D riessen, B.J. Verhaar, and J.T.M. W alraven, Phys. Rev. Lett. 53, 1919 (1984).